G3VM-81HR

New High-capacity MOS FET Relays Allowing Switching of a 1.25-A **Continuous Load Current with a 80-V** Load Voltage.

- Continuous load current of 1.250 mA.
- Dielectric strength of 1,500 Vrms between I/O.

■ Application Examples

- Broadband systems
- Measurement devices
- Data loggers
- Amusement machines

■List of Models





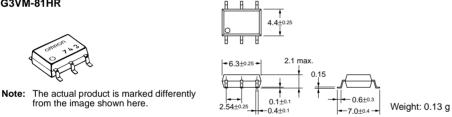
Note: The actual product is marked differently from the image shown here.

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	80 VAC	G3VM-81HR	75	
	terminals		G3VM-81HR(TR)		2,500

Dimensions

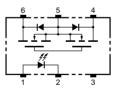
Note: All units are in millimeters unless otherwise indicated.

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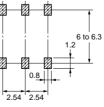


Terminal Arrangement/Internal Connections (Top View)

G3VM-81HR



■ Actual Mounting Pad Dimensions (Recommended Value, Top View) G3VM-81HR



■ Absolute Maximum Ratings (Ta = 25°C)

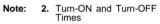
Item		Symbol	ol Rating U		Measurement Conditions
Input LED forward current		I _F	50	mA	
	Repetitive peak LED forward current	I _{FP}	1	А	100 μs pulses, 100 pps
	LED forward current reduction rate	$\Delta I_{\rm F}^{\rm o}{\rm C}$	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V _R	5	V	
	Connection temperature	Тj	125	°C	
Output	Output dielectric strength	V _{OFF}	80	V	
	Continuous load current	I _O	1,250	mA	
	ON current reduction rate	$\Delta I_{ON} / ^{\circ}C$	-12.5	mA/°C	Ta ≥ 25°C
	Connection temperature	Тj	125	°C	
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		Та	-20 to +85	°C	With no icing or condensation
Storage	Storage temperature		-40 to +125	°C	With no icing or condensation
Soldering temperature (10 s)		T _{stg}	260	°C	10 s

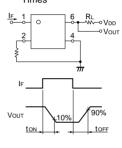
Note:

 The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	Item	Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R			10	μA	V _R = 5 V	
	Capacity between terminals	CT		15		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}		2	5	mA	l _O = 1,250 mA	
Output	Maximum resistance with output ON	R _{ON}		0.11	0.15	Ω	I _F = 5 mA, I _O = 1,250 mA	
	Current leakage when the relay is open	I _{LEAK}		1.2	1.5	nA	V _{OFF} = 20 V, Ta = 50°C	
Capacity	/ between I/O terminals	C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			MΩ	$\label{eq:VI-O} \begin{split} V_{I\text{-}O} &= 500 \ \text{VDC}, \\ \text{RoH} \leq 60\% \end{split}$	
Turn-ON time		tON		2.0	3.0	ms	$I_F = 5 \text{ mA}, \text{ R}_L = 200 \Omega,$	
Turn-OFF time		tOFF		0.7	1.0	ms	$V_{DD} = 20 V$ (See note 2.)	





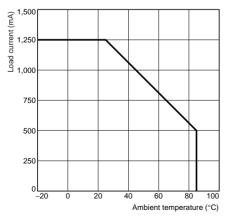
Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			64	V
Operating LED forward current	I _F	5		30	mA
Continuous load current	I _O			1,250	mA
Operating temperature	Ta	25		60	°C

Engineering Data

Load Current vs. Ambient Temperature G3VM-81HR



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.